NPN Small-Signal Darlington Transistor

This NPN small signal Darlington transistor is designed for use in switching applications, such as print hammer, relay, solenoid and lamp drivers. The device is housed in the SOT-223 package, which is designed for medium power surface mount applications.

Features

- The SOT-223 Package can be soldered using wave or reflow. The formed leads absorb thermal stress during soldering, eliminating the possibility of damage to the die
- Available in 12 mm Tape and Reel
 Use BSP52T1 to Order the 7 Inch/1000 Unit Reel
- PNP Complement is BSP62T1
- These Devices are Pb-Free, Halogen Free/BFR Free and are RoHS Compliant

MAXIMUM RATINGS (T_C = 25°C unless otherwise noted)

Rating	Symbol	Max	Unit
Collector-Emitter Voltage	V _{CES}	80	V
Collector-Base Voltage	V _{CBO}	90	V
Emitter-Base Voltage	V _{EBO}	5.0	V
Collector Current	I _C	1.0	Α
Total Power Dissipation (Note 1) @ T _A = 25°C Derate above 25°C	P _D	0.8 6.4	W mW/°C
Total Power Dissipation (Note 2) @ T _A = 25°C Derate above 25°C	P _D	1.25 10	W mW/°C
Operating and Storage Temperature Range	T _J , T _{stg}	-65 to 150	°C

THERMAL CHARACTERISTICS

Characteristic	Symbol	Value	Unit
Thermal Resistance (Note 1) Junction-to-Ambient	$R_{\theta JA}$	156	°C/W
Thermal Resistance (Note 2) Junction-to-Ambient	$R_{\theta JA}$	100	°C/W
Maximum Temperature for Soldering Purposes Time in Solder Bath	TL	260 10	°C Sec

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

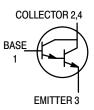
- Device mounted on a FR-4 glass epoxy printed circuit board using minimum recommended footprint.
- 2. Device mounted on a FR-4 glass epoxy printed circuit board using 1 cm² pad.



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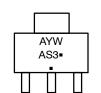
http://onsemi.com

MEDIUM POWER NPN SILICON SURFACE MOUNT DARLINGTON TRANSISTOR



1 2 3

SOT-223 CASE 318E STYLE 1



MARKING DIAGRAM

A = Assembly Location

Y = Year W = Work Week

AS3 = Specific Device Code = Pb-Free Package

(Note: Microdot may be in either location)

ORDERING INFORMATION

Device	Package	Shipping [†]
BSP52T1G	SOT-223 (Pb-Free)	1000 / Tape & Reel
BSP52T3G	SOT-223 (Pb-Free)	4000 / Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

ELECTRICAL CHARACTERISTICS (T_A = 25°C unless otherwise noted)

Characteristics	Symbol	Min	Тур	Max	Unit
OFF CHARACTERISTICS		•	•		
Collector-Base Breakdown Voltage ($I_C = 100 \mu A$, $I_E = 0$)	V _(BR) CBO	90	-	-	V
Emitter-Base Breakdown Voltage ($I_E = 10 \mu A, I_C = 0$)	V _{(BR)EBO}	5.0	_	_	V
Collector-Emitter Cutoff Current (V _{CE} = 80 V, V _{BE} = 0)	I _{CES}	_	_	10	μА
Emitter-Base Cutoff Current $(V_{EB} = 4.0 \text{ V, } I_{C} = 0)$	I _{EBO}	_	-	10	μΑ
ON CHARACTERISTICS (Note 3)					
DC Current Gain (I _C = 150 mA, V _{CE} = 10 V) (I _C = 500 mA, V _{CE} = 10 V)	h _{FE}	1000 2000	_ _	_ _	_
Collector-Emitter Saturation Voltage (I _C = 500 mA, I _B = 0.5 mA)	V _{CE(sat)}	_	_	1.3	V
Base-Emitter Saturation Voltage ($I_C = 500 \text{ mA}, I_B = 0.5 \text{ mA}$)	V _{BE(sat)}	_	-	1.9	V
SWITCHING CHARACTERISTICS					
Rise Time (V _{CC} = 10 V, I _C = 150 mA, I _{B1} = 0.15 mA)	t _r	-	155	-	ns
Delay Time (V _{CC} = 10 V, I _C = 150 mA, I _{B1} = 0.15 mA)	t _d	-	205	-	ns
Storage Time $(V_{CC} = 10 \text{ V}, I_C = 150 \text{ mA}, I_{B1} = 0.15 \text{ mA}, I_{B2} = 0.15 \text{ mA})$	t _s	_	420	-	ns
Fall Time $(V_{CC} = 10 \text{ V}, I_{C} = 150 \text{ mA}, I_{B1} = 0.15 \text{ mA}, I_{B2} = 0.15 \text{ mA})$	t _f	_	365	_	ns

^{3.} Pulse Test: Pulse Width ≤ 300 μs, Duty Cycle ≤ 2.0%

TYPICAL CHARACTERISTICS (T_J = 25°C unless otherwise noted)

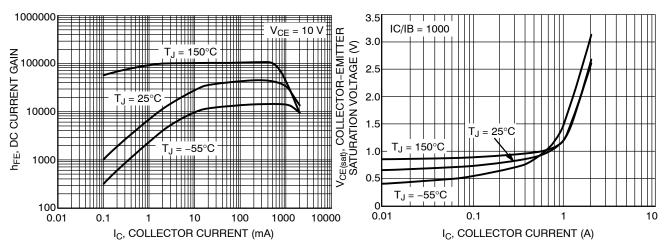


Figure 1. DC Current Gain

Figure 2. Collector-Emitter Saturation Voltage

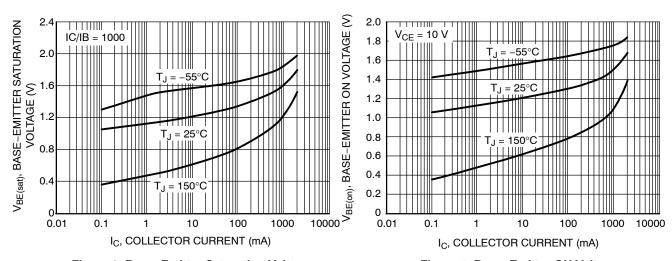


Figure 3. Base-Emitter Saturation Voltage

Figure 4. Base-Emitter ON Voltage

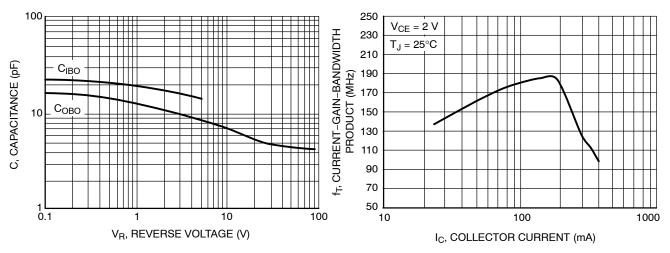
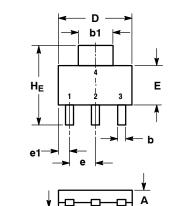


Figure 5. Capacitance

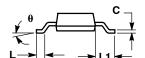
Figure 6. Current Gain Bandwidth Product vs.
Collector Current

PACKAGE DIMENSIONS

SOT-223 (TO-261) CASE 318E-04 **ISSUE N**



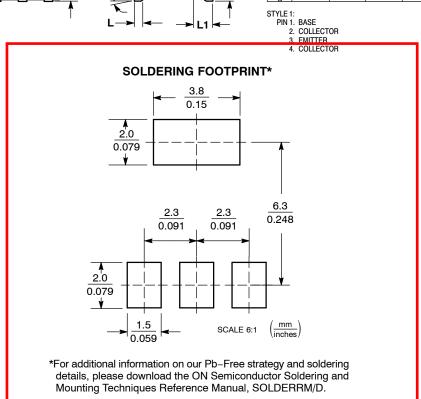
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NOTES:

- DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
- CONTROLLING DIMENSION: INCH.

	MILLIMETERS			INCHES			
DIM	MIN	NOM	MAX	MIN	NOM	MAX	
Α	1.50	1.63	1.75	0.060	0.064	0.068	
A1	0.02	0.06	0.10	0.001	0.002	0.004	
b	0.60	0.75	0.89	0.024	0.030	0.035	
b1	2.90	3.06	3.20	0.115	0.121	0.126	
С	0.24	0.29	0.35	0.009	0.012	0.014	
D	6.30	6.50	6.70	0.249	0.256	0.263	
E	3.30	3.50	3.70	0.130	0.138	0.145	
е	2.20	2.30	2.40	0.087	0.091	0.094	
e1	0.85	0.94	1.05	0.033	0.037	0.041	
L	0.20			0.008			
L1	1.50	1.75	2.00	0.060	0.069	0.078	
HE	6.70	7.00	7.30	0.264	0.276	0.287	
θ	0°	_	10°	0°	-	10°	



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